NSN 5961-01-181-2667

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-181-2667 **Inclosure Material:** Metal **Overall Length:** 1.573 inches **Overall Height:** 0.420 inches **Overall Width:** 1.050 inches **Mounting Facility Quantity: Internal Configuration:** Field effect **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case and quality assurance level tx **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 100.0 drain to source voltage and 100.0 drain to gate voltage and 20.0 gate to source voltage **Current Rating Per Characteristic:** 24.00 amperes dark current and 38.00 amperes off-state current, peak **Power Rating Per Characteristic:** 1.2 watts total power dissipation **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Test Data Document:** 81349-mil-prf-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 2 unthreaded hole and 1 case **Specification Data:** 81349-mil-prf-19500/543 government specification Shelf Life: N/a **Unit Of Measure: Demilitarization:**

Mil-prf-19500 spec.

Mil-std (military Standard):

No Fiig: A110a0